

RJH60M3DPQ-E0

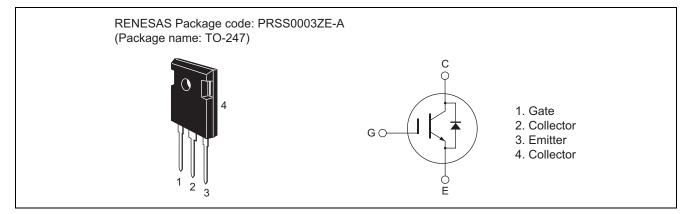
600V - 17A - IGBT Application: Inverter R07DS1086EJ0200 Rev.2.00 Jun 13, 2013

Features

- Short circuit withstand time (8 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.8$ V typ. (at $I_C = 17$ A, $V_{GE} = 15$ V, $Ta = 25^{\circ}C$)
- Built in fast recovery diode (100 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching

 $t_f = 70$ ns typ. (at $V_{CC} = 300$ V, $V_{GE} = 15$ V, $I_C = 17$ A, Rg = 5 Ω , $Ta = 25^{\circ}C$)

Outline



Absolute Maximum Ratings

				(Ta = 25°C)
Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	600	V
Gate to emitter voltage		V _{GES}	±30	V
Collector current	$Tc = 25^{\circ}C$	Ι _C	35	A
	Tc = 100°C	Ι _C	17	A
Collector peak current		I _C (peak) ^{Note1}	50	A
Collector to emitter diode forward current		I _{DF}	17	A
Collector to emitter diode forward peak current		I _{DF} (peak) ^{Note1}	50	A
Collector dissipation		Pc ^{Note2} 127		W
Junction to case thermal resistance (IGBT)			θj-c ^{Note2} 1.25	
Junction to case thermal resistance (Diode)		θj-cd ^{Note2}	2.3	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. $PW \le 10 \ \mu s$, duty cycle $\le 1\%$

2. Value at Tc = 25°C



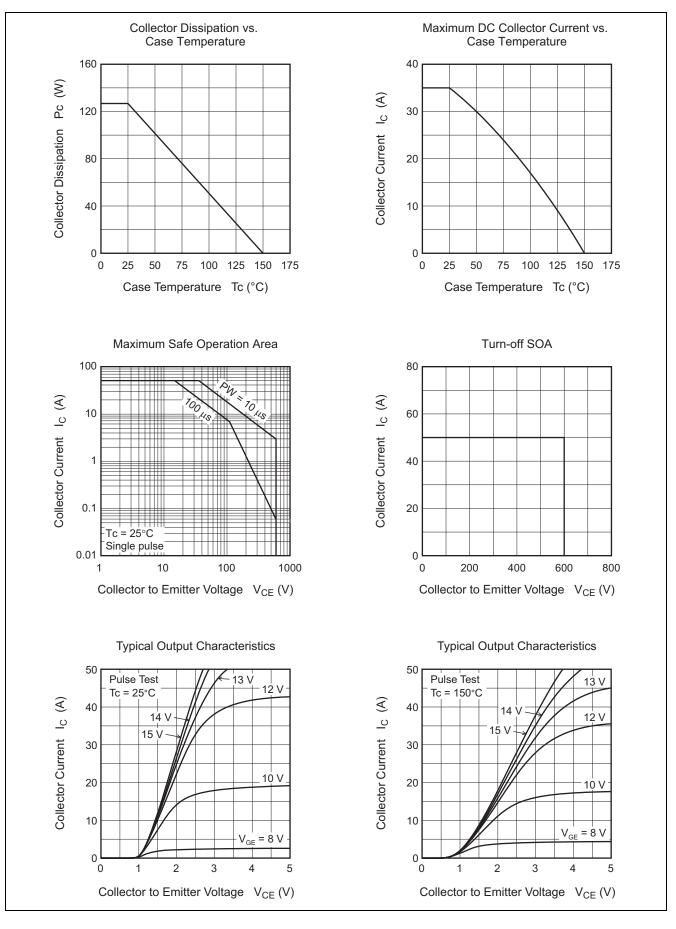
Electrical Characteristics

	-		•	•		$(Ta = 25^{\circ}C)$	
ltem	Symbol	Min	Тур	Max	Unit	Test Conditions	
Zero gate voltage collector current / Diode reverse current	I_{CES}/I_{R}	—	—	5	μΑ	$V_{CE} = 600 \text{ V}, \text{ V}_{GE} = 0$	
Gate to emitter leak current	I _{GES}	_	—	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$	
Gate to emitter cutoff voltage	$V_{\text{GE(off)}}$	5	—	7	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	
Collector to emitter saturation voltage	V _{CE(sat)}		1.8	2.3	V	$I_{C} = 17 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
	V _{CE(sat)}	_	2.4	—	V	$I_{C} = 35 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies	_	900	—	pF	V _{CE} = 25 V	
Output capacitance	Coes	_	65	—	pF	$V_{GE} = 0$	
Reverse transfer capacitance	Cres	_	35	—	pF	f = 1 MHz	
Total gate charge	Qg	_	60	—	nC	V _{GE} = 15 V	
Gate to emitter charge	Qge	_	9	—	nC	V _{CE} = 300 V	
Gate to collector charge	Qgc	_	35	—	nC	$I_{\rm C} = 17$ A	
Turn-on delay time	t _{d(on)}	_	40	—	ns	V _{CC} = 300 V	
Rise time	tr	_	20	—	ns	$V_{GE} = 15 V$ $I_{C} = 17 A$ $Rg = 5 \Omega$	
Turn-off delay time	$t_{d(off)}$	_	90	—	ns		
Fall time	t _f	_	80	—	ns		
Turn-on energy	Eon	_	0.29	—	mJ	 Inductive load 	
Turn-off energy	E _{off}	_	0.29	—	mJ		
Total switching energy	E _{total}	_	0.58	—	mJ		
Short circuit withstand time	t _{sc}	6	8	_	μs	Tc = 100 °C	
						$V_{CC} \leq 360~V,~V_{GE} = 15~V$	
FRD Forward voltage	VF		1.3	1.7	V	$I_F = 17 A^{Note3}$	
FRD reverse recovery time	t _{rr}		100	—	ns	I _F = 17 A	
FRD reverse recovery charge	Qrr		0.14	—	μC	di _F /dt = 100 A/µs	
FRD peak reverse recovery current	l _{rr}		4.1		А		

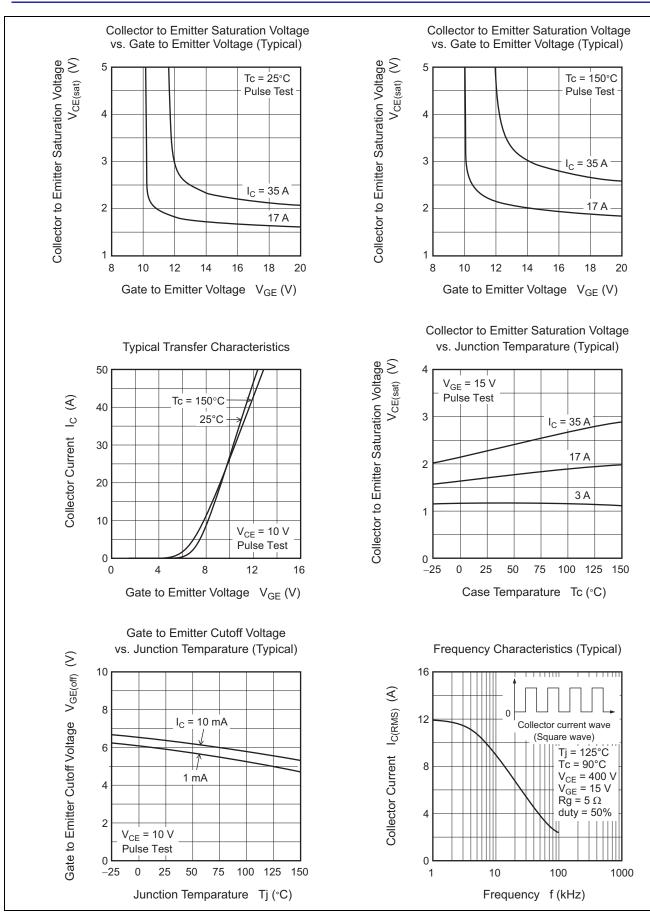
Notes: 3. Pulse test.



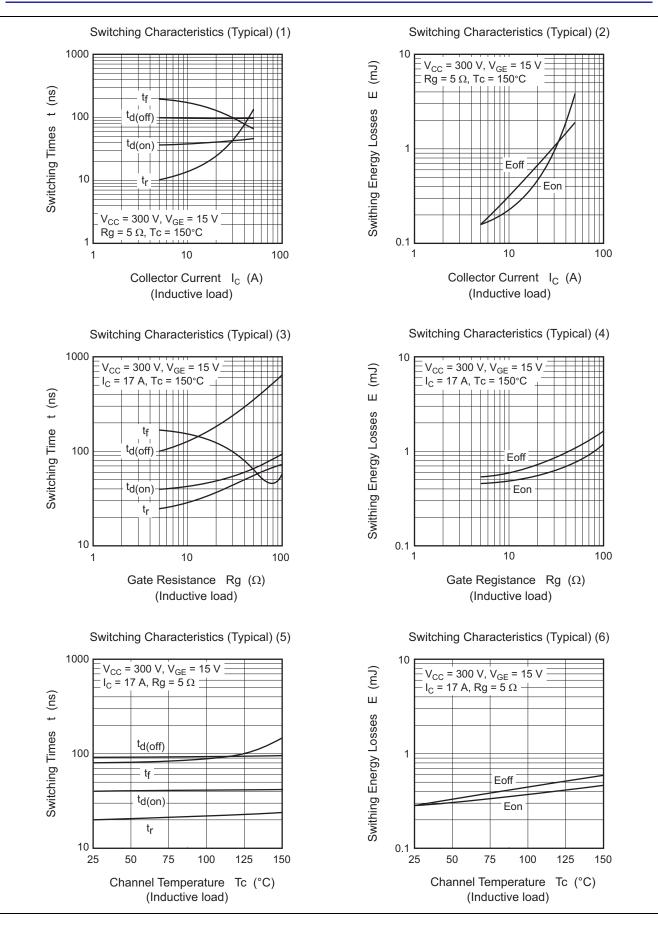
Main Characteristics



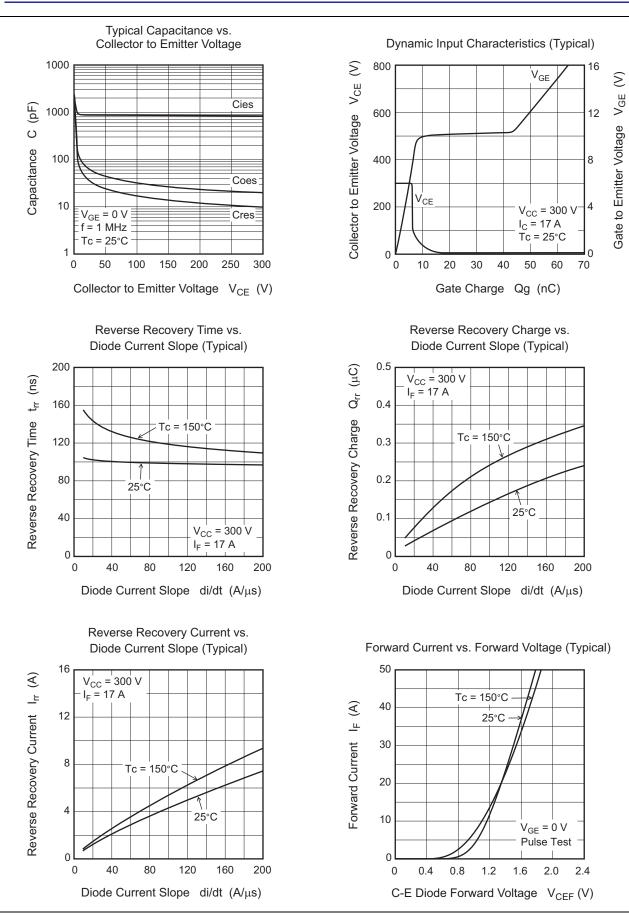


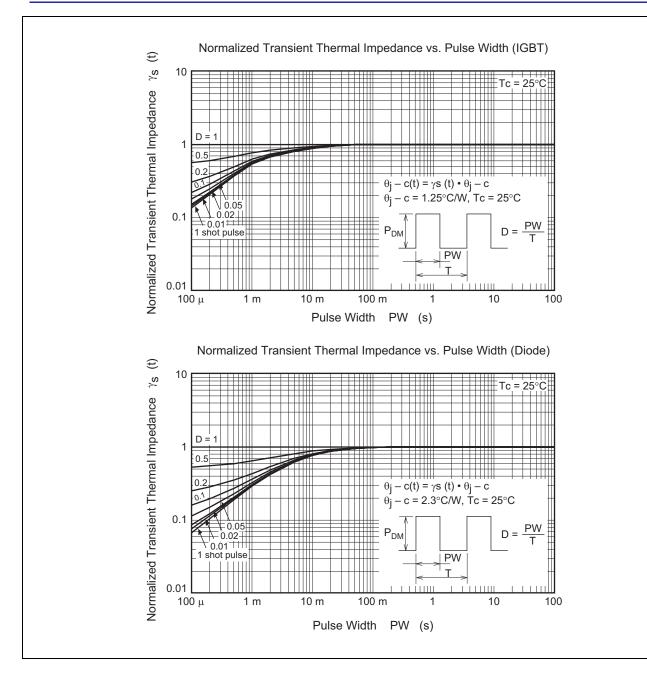




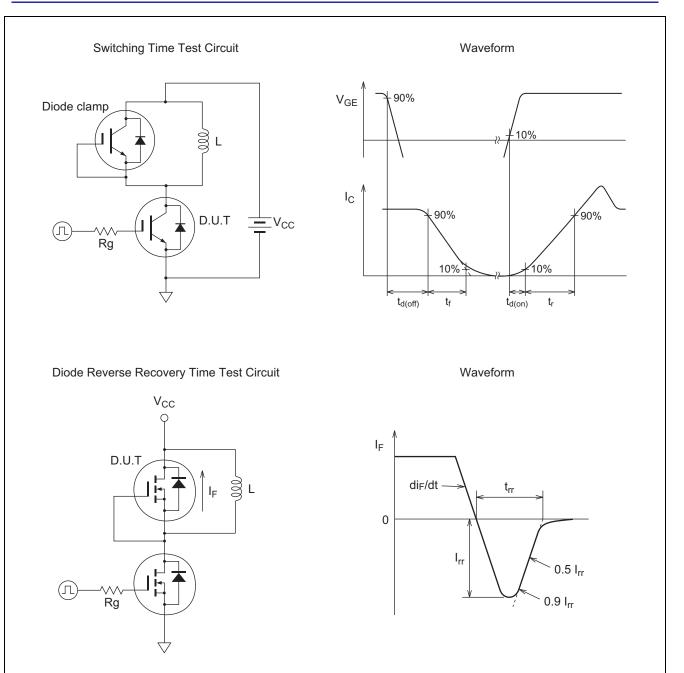






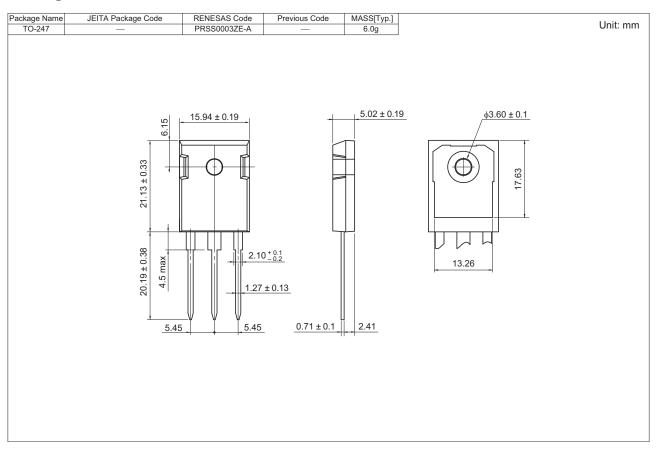








Package Dimension



Ordering Information

Orderable Part No.	Quantity	Shipping Container
RJH60M3DPQ-E0#T2	450 pcs	Tube



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